

# < High-power GaAs FET (small signal gain stage) >

# **MGF0911A**

**L & S BAND / 12W** non - matched

#### **DESCRIPTION**

The MGF0911A, GaAs FET with an N-channel schottky gate, is designed for use in UHF band amplifiers.

## **FEATURES**

- Class A operation
- · High output power P1dB=41.0dBm(TYP.) @f=2.3GHz
- High power gain

GLP=11.0dB(TYP.) @f=2.3GHz

High power added efficiency

P.A.E = 40%(TYP.)@f=2.3GHz,P1dB

• Hermetically sealed metal-ceramic package with ceramic lid

## **APPLICATION**

• For UHF Band power amplifiers

#### **QUALITY**

• IG

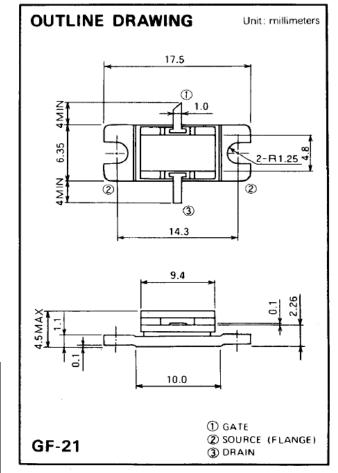
## RECOMMENDED BIAS CONDITIONS

• Vds=10V • Ids=2.6A • Rg=50 $\Omega$  Refer to Bias Procedure

## Absolute maximum ratings (Ta=25°C)

| Symbol | Parameter               | Ratings     | Unit |
|--------|-------------------------|-------------|------|
| VGDO   | Gate to drain voltage   | -15         | V    |
| VGSO   | Gate to source voltage  | -15         | V    |
| ID     | Drain current           | 10          | Α    |
| IGR    | Reverse gate current    | -30         | mA   |
| IGF    | Forward gate current    | 63          | mA   |
| PT*1   | Total power dissipation | 37.5        | W    |
| Tch    | Cannel temperature      | 175         | °C   |
| Tstg   | Storage temperature     | -65 to +175 | °C   |

<sup>\*1:</sup>Tc=25°C



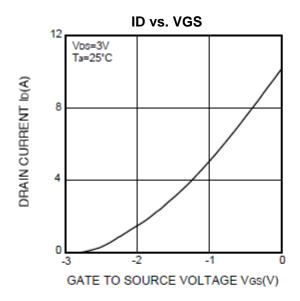
## Electrical characteristics (Ta=25°C)

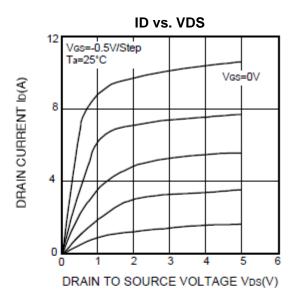
| Symbol       | Parameter                            | Test conditions         |      | Limits |      |      |
|--------------|--------------------------------------|-------------------------|------|--------|------|------|
|              |                                      |                         | Min. | Тур.   | Max. |      |
| IDSS         | Saturated drain current              | VDS=3V,VGS=0V           | -    | -      | 10   | Α    |
| gm           | Transconductance                     | VDS=3V,ID=2.6A          | -    | 3      | -    | S    |
| VGS(off)     | Gate to source cut-off voltage       | VDS=3V,ID=20mA          | -2   | -      | -5   | V    |
| P1dB         | Output power at 1dB gain compression | VDS=10V,ID(RF off)=2.6A | 40   | 41     | -    | dBm  |
| GLP          | Linear Power Gain                    | f=2.3GHz                | 10   | 11     | -    | dB   |
| P.A.E.       | Power added efficiency               |                         | -    | 40     | -    | %    |
| Rth(ch-c) *2 | Thermal resistance                   | Δ Vf method             | -    | -      | 4.0  | °C/W |

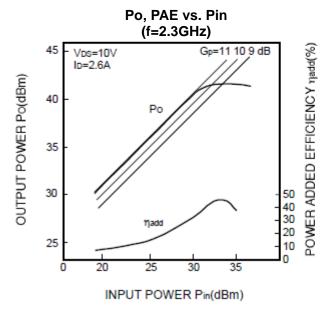
<sup>\*2 :</sup>Channel-case

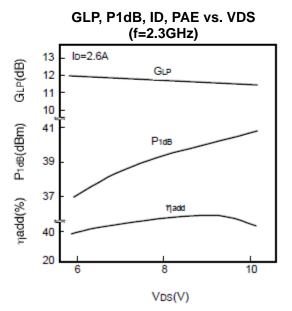
non - matched

## MGF0911A TYPICAL CHARACTERISTICS (Ta=25deg.C)







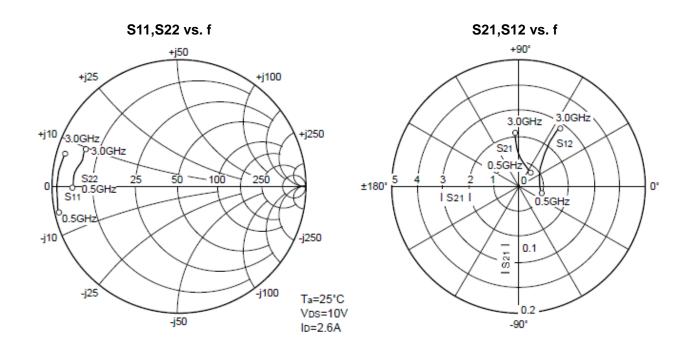


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# $\textbf{MGF0911A S-parameters}(\ \texttt{Ta=25deg.C}\ ,\ \texttt{VDS=10(V),IDS=2.6(A)}\ )$



| Freq.<br>(GHz) | S11   |             | S21   |             | S12   |             | S22   |             | К     | MSG/MAG |
|----------------|-------|-------------|-------|-------------|-------|-------------|-------|-------------|-------|---------|
|                | Magn. | Angle(deg.) | Magn. | Angle(deg.) | Magn. | Angle(deg.) | Magn. | Angle(deg.) | K     | (dB)    |
| 0.50           | 0.986 | -167.3      | 2.046 | 91.2        | 0.008 | 44.1        | 0.913 | -178.6      | 0.515 | 23.1    |
| 0.60           | 0.985 | -171.3      | 1.833 | 87.9        | 0.010 | 44.2        | 0.911 | -179.9      | 0.567 | 22.7    |
| 0.70           | 0.984 | -174.3      | 1.515 | 86.1        | 0.011 | 44.6        | 0.909 | 178.6       | 0.583 | 21.8    |
| 0.80           | 0.983 | -175.5      | 1.356 | 83.6        | 0.012 | 44.9        | 0.907 | 178.2       | 0.675 | 21.2    |
| 0.90           | 0.982 | -172.1      | 1.233 | 84.0        | 0.013 | 45.3        | 0.904 | 177.7       | 0.683 | 20.3    |
| 1.00           | 0.981 | -173.9      | 1.128 | 81.1        | 0.013 | 45.8        | 0.902 | 176.6       | 0.713 | 19.6    |
| 1.10           | 0.980 | -175.3      | 1.033 | 79.7        | 0.015 | 46.4        | 0.898 | 175.7       | 0.736 | 19.3    |
| 1.20           | 0.979 | -176.3      | 0.970 | 77.8        | 0.015 | 46.8        | 0.895 | 176.6       | 0.785 | 18.7    |
| 1.30           | 0.978 | -176.9      | 0.919 | 75.8        | 0.016 | 47.0        | 0.889 | 176.0       | 0.815 | 18.2    |
| 1.40           | 0.976 | -177.9      | 0.878 | 73.6        | 0.017 | 47.3        | 0.883 | 175.6       | 0.835 | 17.5    |
| 1.50           | 0.975 | -178.2      | 0.845 | 71.6        | 0.018 | 47.6        | 0.875 | 175.2       | 0.900 | 17.1    |
| 1.60           | 0.974 | -179.3      | 0.811 | 69.4        | 0.019 | 48.0        | 0.865 | 175.0       | 0.951 | 16.8    |
| 1.70           | 0.973 | -179.8      | 0.788 | 67.8        | 0.020 | 48.4        | 0.858 | 174.6       | 0.989 | 15.8    |
| 1.80           | 0.972 | 179.5       | 0.771 | 65.8        | 0.020 | 48.9        | 0.850 | 173.6       | 1.011 | 14.7    |
| 1.90           | 0.971 | 178.6       | 0.754 | 64.1        | 0.022 | 49.2        | 0.843 | 173.4       | 1.050 | 14.1    |
| 2.00           | 0.970 | 176.7       | 0.653 | 63.1        | 0.023 | 49.6        | 0.837 | 172.6       | 1.149 | 13.9    |
| 2.10           | 0.969 | 175.9       | 0.638 | 60.9        | 0.023 | 49.9        | 0.833 | 174.1       | 1.170 | 13.7    |
| 2.20           | 0.968 | 175.1       | 0.638 | 59.0        | 0.023 | 50.4        | 0.829 | 173.6       | 1.221 | 12.7    |
| 2.30           | 0.967 | 174.1       | 0.635 | 56.3        | 0.024 | 50.7        | 0.826 | 172.9       | 1.242 | 12.3    |
| 2.40           | 0.966 | 173.1       | 0.625 | 54.2        | 0.025 | 51.0        | 0.823 | 171.0       | 1.256 | 11.9    |
| 2.50           | 0.965 | 172.3       | 0.628 | 52.3        | 0.025 | 51.2        | 0.820 | 170.3       | 1.267 | 11.6    |
| 2.60           | 0.965 | 171.2       | 0.634 | 51.3        | 0.027 | 51.6        | 0.818 | 168.8       | 1.292 | 11.4    |
| 2.70           | 0.964 | 170.2       | 0.635 | 48.9        | 0.027 | 51.9        | 0.816 | 167.1       | 1.315 | 11.0    |
| 2.80           | 0.963 | 168.7       | 0.646 | 46.3        | 0.028 | 52.3        | 0.814 | 165.7       | 1.327 | 10.1    |
| 2.90           | 0.962 | 167.6       | 0.642 | 44.0        | 0.029 | 52.5        | 0.812 | 164.6       | 1.366 | 9.8     |
| 3.00           | 0.961 | 166.3       | 0.651 | 41.0        | 0.029 | 52.7        | 0.811 | 162.7       | 1.412 | 9.4     |

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